

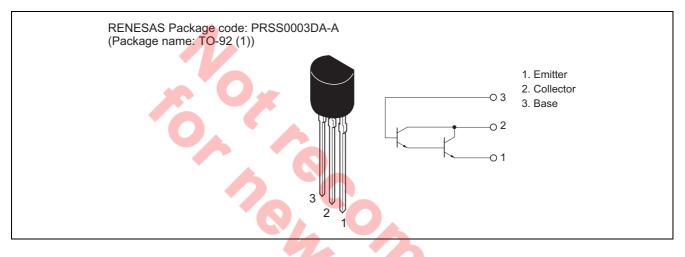
2SC1472(K) Silicon NPN Epitaxial, Darlington

REJ03G0688-0200 (Previous ADE-208-1054) Rev.2.00 Aug.10.2005

Application

High gain amplifier

Outline



Absolute Maximum Ratings

			$(Ta = 25^{\circ}C)$
Item	Symbol	Ratings	Unit
Collector to base voltage	V _{CBO}	40	V
Collector to emitter voltage	V _{CEO}	30	V
Emitter to base voltage	V _{EBO}	10	V
Collector current	Ι _C	300	mA
Collector peak current	i _{C(peak)}	500	mA
Collector power dissipation	Pc	500	mW
Junction temperature	Tj	150	°C
Storage temperature	Tstg	-55 to +150	°C

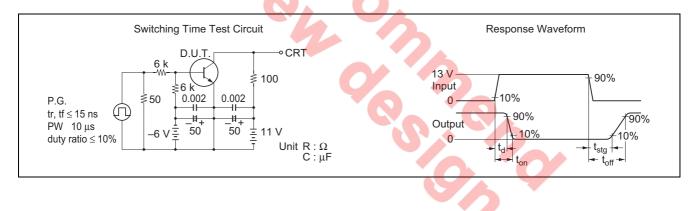


Electrical Characteristics

						$(Ta = 25^{\circ}C)$
Item	Symbol	Min	Тур	Max	Unit	Test conditions
Collector to emitter breakdown voltage	V _{(BR)CEO}	30	—	—	V	$I_{C} = 1 \text{ mA}, R_{BE} = \infty$
Collector cutoff current	I _{CBO}	—	_	100	nA	$V_{CB} = 30 \text{ V}, \text{ I}_{E} = 0$
Emitter cutoff current	I _{EBO}	_	_	100	nA	$V_{EB} = 10 \text{ V}, \text{ I}_{C} = 0$
DC current transfer ratio	h _{FE1} * ¹	2000	_	100000		$I_{C} = 10 \text{ mA}, V_{CE} = 5 \text{ V}$
	h _{FE2} *1	3000	—	—		$I_C = 100 \text{ mA}, V_{CE} = 5 \text{ V}$ (Pulse Test)
	h _{FE3} *1	3000	—			$I_C = 400 \text{ mA}, V_{CE} = 5 \text{ V}$ (Pulse Test)
Collector to emitter saturation voltage	V _{CE(sat)}	—	—	1.5	V	$I_{C} = 100 \text{ mA}, I_{B} = 0.1 \text{ mA}$
Base to emitter voltage	V _{BE(sat)}	—	—	2.0	V	$I_{\rm C} = 100 \text{ mA}, I_{\rm B} = 0.1 \text{ mA}$
Gain bandwidth product	f⊤	50	—	—	MHz	$V_{CE} = 5 \text{ V}, I_{C} = 10 \text{ mA}$
Collector output capacitance	Cob	—	—	10	pF	$V_{CB} = 10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$
Turn on time	t _{on}	_	60	—	ns	$V_{CC} = 11 V$ $I_{C} = 100 I_{B1} = 100 mA$ $I_{B2} = -I_{B1}$
Turn off time	t _{off}		800	_	ns	
Storage time	t _{stg}	—	350	—	ns	

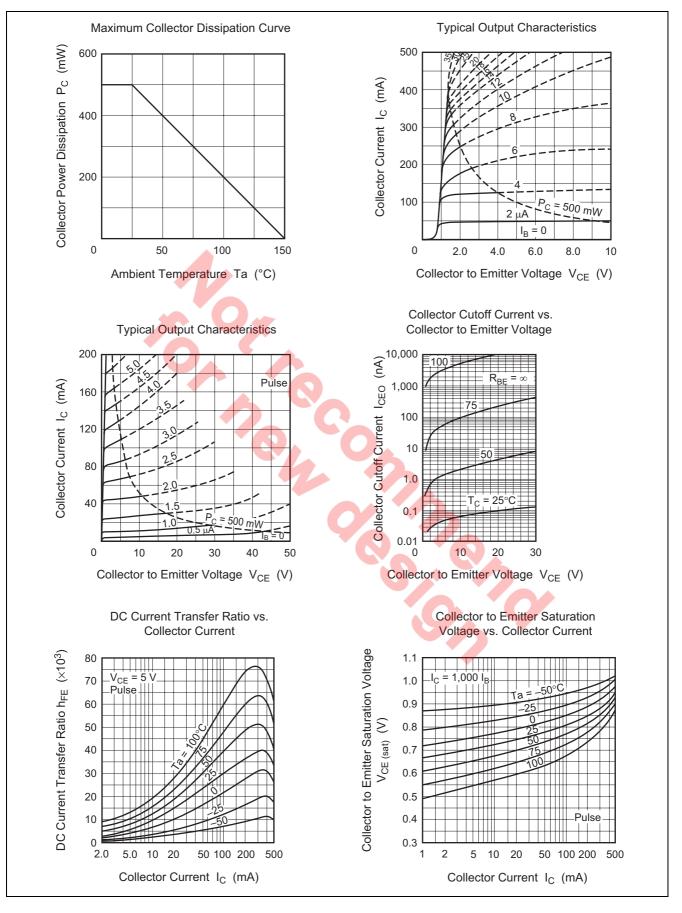
Note: 1. The 2SC1472(K) is grouped by h_{FE} as follows.

	Α	В
h _{FE1}	2000 to 100000	5000 to 100000
h _{FE2}	3000 min	10000 min
h _{FE3}	3000 min	10000 min

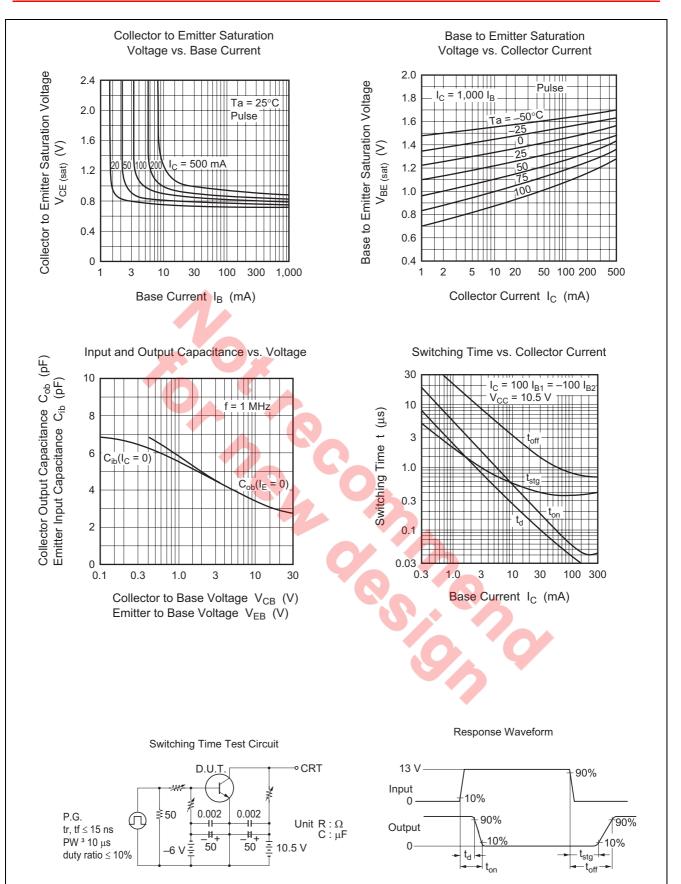




Main Characteristics

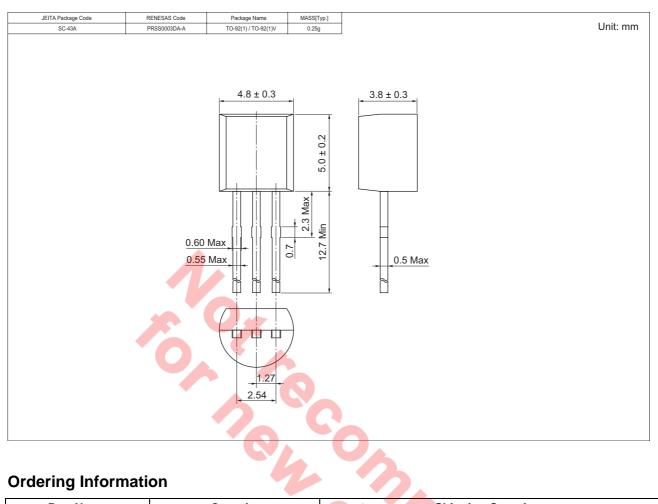








Package Dimensions



Ordering Information

Part Name	Quantity	Shipping Container
2SC1472KATZ-E	2500	Hold Box, Radial Taping
2SC1472KBTZ-E		

Note: For some grades, production may be terminated. Please contact the Renesas sales office to check the state of production before ordering the product.



Renesas Technology Corp. sales Strategic Planning Div. Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan

Keep safety first in your circuit designs! 1. Renesas Technology Corp. puts the maximum effort into making semiconductor products better and more reliable, but there is always the possibility that trouble may occur with them. Trouble with semiconductors may lead to personal injury, fire or property damage. Remember to give due consideration to safety when making your circuit designs, with appropriate measures such as (i) placement of substitutive, auxiliary circuits, (ii) use of nonflammable material or (iii) prevention against any malfunction or mishap.

- Notes regarding these materials
 1. These materials are intended as a reference to assist our customers in the selection of the Renesas Technology Corp. product best suited to the customer's application; they do not convey any license under any intellectual property rights, or any other rights, belonging to Renesas Technology Corp. or a third party.
 2. Renesas Technology Corp. assumes no responsibility for any damage, or infringement of any third-party's rights, originating in the use of any product data, diagrams, charts, programs, algorithms, or circuit application examples contained in these materials.
 3. All information contained in these materials, and are subject to change by Renesas Technology Corp. without notice due to product distributor for the latest product information before purchasing a product listed herein.
 The information described here may contain technical inaccuracies or typographical errors.
 Renesas Technology Corp. assumes no responsibility for any damage, liability, or other loss rising from these inaccuracies or errors.
 Please also pay attention to information contained in these materials, including product data, diagrams, charts, programs, and algorithms, please be sure to evaluate all information as a total system before making a final decision on the applicability of the information and products. Renesas Technology Corp. semiconductors are not designed or manufactured for use in a device or system that is used under circumstances in which human life is potentially at stake. Please contain denesas Technology Corp. or an authorized for use in a device or system that is used under circumstances in which human life is potentially at stake. Please contain tenses as technology Corp. or an authorized for use in a device or system that is used under circumstances in which human life is potentially at stake. Please contain tenses as technology Corp. or an authorized for use in a device or system that is used under circumstances in

- use. 6. The prior written approval of Renesas Technology Corp. is necessary to reprint or reproduce in whole or in part these materials. 7. If these products or technologies are subject to the Japanese export control restrictions, they must be exported under a license from the Japanese government and cannot be imported into a country other than the approved destination. Any diversion or reexport contrary to the export control laws and regulations of Japan and/or the country of destination is prohibited. 8. Please contact Renesas Technology Corp. for further details on these materials or the products contained therein.



RENESAS SALES OFFICES

Refer to "http://www.renesas.com/en/network" for the latest and detailed information.

Renesas Technology America, Inc. 450 Holger Way, San Jose, CA 95134-1368, U.S.A Tel: <1> (408) 382-7500, Fax: <1> (408) 382-7501

Renesas Technology Europe Limited Dukes Meadow, Millboard Road, Bourne End, Buckinghamshire, SL8 5FH, U.K. Tel: <44> (1628) 585-100, Fax: <44> (1628) 585-900

Renesas Technology Hong Kong Ltd.

7th Floor, North Tower, World Finance Centre, Harbour City, 1 Canton Road, Tsimshatsui, Kowloon, Hong Kong Tel: <852> 2265-6688, Fax: <852> 2730-6071

Renesas Technology Taiwan Co., Ltd. 10th Floor, No.99, Fushing North Road, Taipei, Taiwan Tel: <886> (2) 2715-2888, Fax: <886> (2) 2713-2999

Renesas Technology (Shanghai) Co., Ltd. Unit2607 Ruijing Building, No.205 Maoming Road (S), Shanghai 200020, China Tel: <86> (21) 6472-1001, Fax: <86> (21) 6415-2952

Renesas Technology Singapore Pte. Ltd.

1 Harbour Front Avenue, #06-10, Keppel Bay Tower, Singapore 098632 Tel: <65> 6213-0200, Fax: <65> 6278-8001

Renesas Technology Korea Co., Ltd. Kukje Center Bldg. 18th Fl., 191, 2-ka, Hangang-ro, Yongsan-ku, Seoul 140-702, Korea Tel: <82> 2-796-3115, Fax: <82> 2-796-2145

Renesas Technology Malaysia Sdn. Bhd.

Unit 906, Block B, Menara Amcorp, Amcorp Trade Centre, No.18, Jalan Persiaran Barat, 46050 Petaling Jaya, Selangor Darul Ehsan, Malaysia Tel: <603> 7955-9390, Fax: <603> 7955-9510

http://www.renesas.com